SSM SUSUMU





Electrical Specification

Туре	Power ratings		Temperature coefficient of resistance	Resistance range (Ω) Resistance tolerance $(\%)$			Maximum voltage	Resistance value series	Operating temperature	Pakaging quantity	
	Low	Regular	High	(ppm/°C)	±0.05% (W)	±0.1% (B)	±0.5%(D)				
		1/16W	1/8W	±5(V)		100≦R<3k			00V E-24, E-96	-55°C ~ 155°C	T5
RG1005	1/32W			±10(N)		47≦R≦100k]			10
				±25(P)		47≦R≦150k		75V			T10
				±100(R)	_	—	10≦R<47				
	1/16W	1/10W	1/6W	±5(V)		100≦R<5.1k					Τ5
504000				±10(N)		47≦R≦274k					
RG1608				±25(P)	47≦R≦274k	47≦F	R≦1M	1000			
				±50(Q)	_	—	10≦R<47				
	1/10W	1/8W	1/4W	±5(V)		100≦R<10.2k					
BG2012				±10(N)		47≦R≦475k		150V			
RG2012				±25(P)	47≦R≦475k	47≦R≦	≦2.7M	1300			
				±50(Q)	_	_	10≦R<47				
				±5(V)		100≦R≦33.2k					
RG3216	1/8W	1/4W		±10(N)	47≦R≦1M			200V			
100210				±25(P)		47≦R≦5.1M					
				±50(Q)	_	_	10≦R<47				

Dimensions



Туре	Size (inch)	L	W	а	b	t	
RG1005	0402	1.00+0.1/-0.05	0.50±0.05	0.20±0.10	0.25±0.05	0.35±0.05	
RG1608	0603	1.60±0.20	0.80±0.20	0.30±0.20	0.30±0.20	0.40±0.10	
RG2012	0805	2.00±0.20	1.25±0.20	0.40±0.20	0.40±0.20	0.40±0.10	
RG3216	3216 1206 3.20±0.20		1.60±0.20	0.50±0.25	0.50±0.20	0.40±0.10	
						(unit · mm)	

(unit : mm)

Thin film surface mount resistors

SSMSUSUMU

Reliability specification			Low		Regular		High		
Test Items	Condition (test methods)	≦47Ω	≧47Ω	≦47Ω	≧47Ω	≦47Ω	≧47Ω	Low	
Short time overload	2.5 x rated voltage, ^{*1} 5 seconds	±0.10%	±0.05%	±0.10%	±0.05%	-	±0.10%	±(0.01%)	
Life (biased)	70°C, rated voltage,1 90min on 30min off, 1000hours	±0.25%	±0.10%	±0.50%	±0.25%	_	±0.50%	±(0.01%)	
High temperature high humidity	85°C, 85%RH, 1/10 of rated power,	±0.25%	±0.10%	±0.50%	±0.25%	_	±0.50%	±(0.05%)	
	90min on 30min off, 1000hours								
Temperature shock	-55°C (30min) \sim 125°C (30min) 1000cycles	±0.25%	±0.10%	±0.25%	±0.10%	-	±0.10%	±(0.01%)	
High temperature exposure	155°C, no bias, 1000hours	±0.25%	±0.10%	±0.25%	±0.10%	_	±0.10%	±(0.01%)	
Resistance to soldering heat	260±5°C, 10 seconds (reflow)	±0.1%	±0.1%	±0.1%	±0.1%	_	±0.1%	±(0.01%)	
*1 Rated voltage is given by $E = \sqrt{R \times P}$ $E = rated voltage (V), R = nominal resistance value(\Omega), P = rated power(W)$									

1 Rated voltage is given by $E = \sqrt{R \times P}$ E = rated voltage (V), R=nominal resistance value(Ω), P=rated power(W) If rated voltage exceeds maximum voltage /element, maximum voltage/element is the rated voltage.

10000 hour reliability test data

OBiased life test



OTemperature shock



Derating Curve



Maximum pulse power limit



Test procedure

Voltage pulse is applied to the test samples mounted on the test board.

After each pulse, resistance drift is measured. Pulse voltage is increased until the drift exceeds +/-0.5%. The power at that voltage is defined as the maximum pulse power.

OHigh temperature high humidity (biased)



OHigh temperature exposure



RG series